SNx4HC148 8 线路至 3 路线优先级编码器

1 特性

- 2V 至 6V 的宽工作电压范围
- 输出可驱动多达 10 个 LSTTL 负载
- 低功耗，I_{CC} 最大值为 80 μA
- t_{pd} 典型值 = 16 ns
- ±4 mA 输出驱动（在 5V 时）
- 低输入电流，最大值 1 μA
- 将八条数据线编码为 3 线二进制文件（八进制）

2 应用

- N 位编码
- 代码转换器和生成器

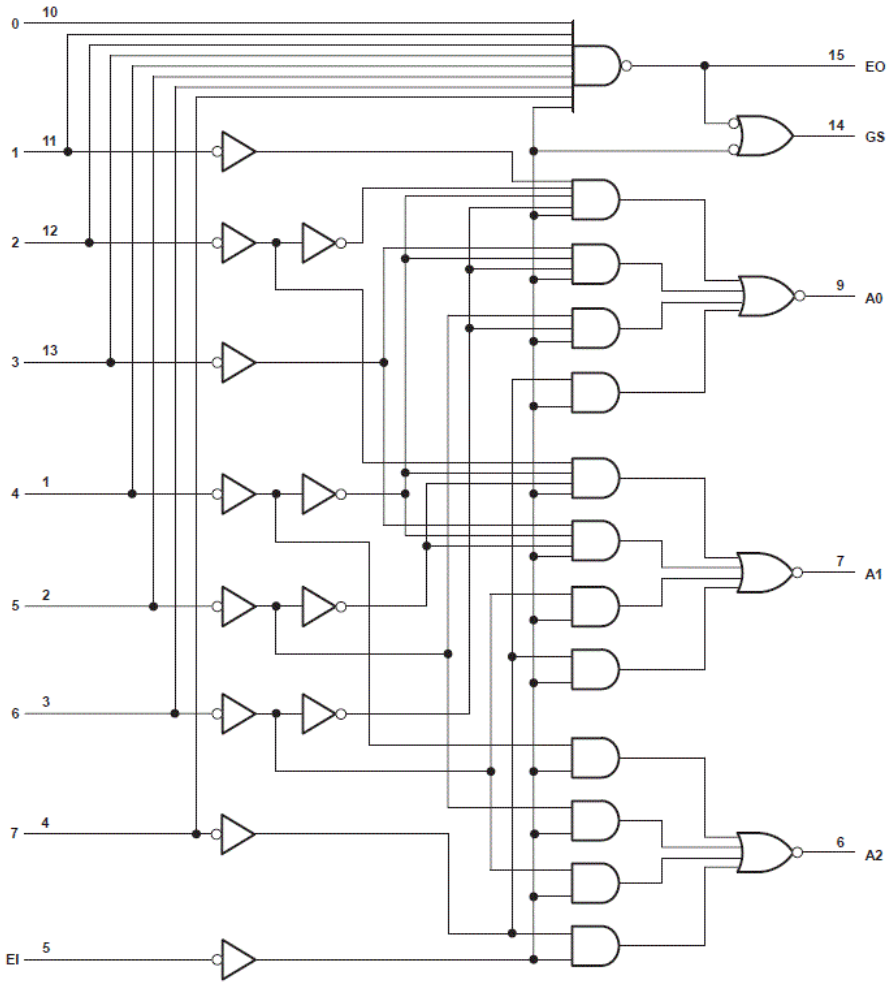
3 说明

SNx4HC148 是一款 8 输入优先级编码器。添加了输入使能 (EI) 和输出使能 (EO) 信号，允许级联多个级，而无需添加外部电路。

器件信息(1)

器件型号	封装	封装尺寸（标称值）
SN74HC148D	SOIC (16)	9.90mm × 3.90mm
SN74HC148N	PDIP (16)	19.31mm × 6.35mm
SN74HC148NS	SO (16)	10.20mm × 5.30mm
SN54HC148J	CDIP (16)	21.34mm × 6.92mm
SNJ54HC148FK	LCCC (20)	8.89mm × 8.45mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。



Pin numbers shown are for the D, DW, J, N, NS, and W packages.

功能方框图

本文档旨在为方便起见，提供有关 TI 产品中文版本的信息，以确认产品的概要。有关适用的官方英文版本的最新信息，请访问 www.ti.com，其内容始终优先。TI 不保证翻译的准确性和有效性。在实际设计之前，请务必参考最新版本的英文版本。

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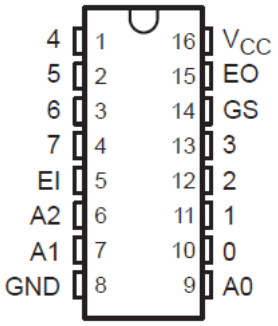
4 Revision History

注：以前版本的页码可能与当前版本的页码不同

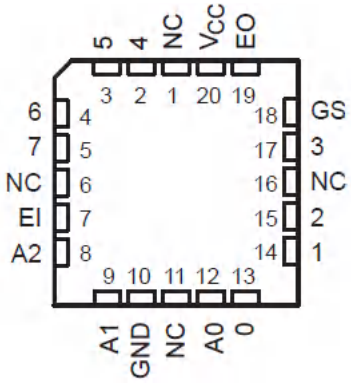
Changes from Revision G (April 2004) to Revision H (March 2022)	Page
• 更新了整个文档中的编号、格式、表格、图和交叉参考，以反映现代数据表标准	1

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5 Pin Configuration and Functions



J, D, N or NS Package
16-Pin CDIP, SOIC, PDIP, SO
Top View



FK Package
20-Pin LCCC
Top View

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	7	V
I_{IK}	Input clamp current	(V_I < 0 or V_I > V_{CC})(2)		±20	mA
I_{OK}	Output clamp current	(V_O < 0 or V_O > V_{CC})(2)		±20	mA
I_O	Continuous output current	(V_O = 0 to V_{CC})		±25	mA
V_{CC} or GND	Continuous current through			±50	mA
T_J	Junction temperature			150	°C
T_{stg}	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

6.2 Recommended Operating Conditions(1)

			SN54HC148			SN74HC148			UNIT
			MIN	NOM		MIN	NOM	MAX	
V_{CC}	Supply voltage		2	5	6	2	5	6	V
V_{IH}	High-level input voltage	V_{CC} = 2V	1.5			1.5			V
		V_{CC} = 4.5V	3.15			3.15			
		V_{CC} = 6V	4.2			4.2			
V_{IL}	Low-level input voltage	V_{CC} = 2V			0.5			0.5	V
		V_{CC} = 4.5V			1.35			1.35	
		V_{CC} = 6V			1.8			1.8	
V_I	Input voltage		0		V_{CC}	0		V_{CC}	V
V_O	Output voltage		0		V_{CC}	0		V_{CC}	V
$\Delta t/\Delta V_{CC}$	Input transition rise/fall time	V_{CC} = 2V			1000			1000	ns
		V_{CC} = 4.5V			500			500	
		V_{CC} = 6V			400			400	
T_A	Operating free-air temperature		-55		125	-40		85	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report *Implications of Slow or Floating SMOS Inputs*, literature number SCBA004.

6.3 Thermal Information

THERMAL METRIC		D (SOIC) 16 PINS	DW (SOIC) 16 PINS	N (PDIP) 16 PINS	NS (SO) 16 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance(1)	73	57	67	64	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC package thermal metrics* application report.

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6.4 Electrical Characteristics

PARAMETER		TEST CONDITIONS(1)	V_{CC}	T_A = 25°C			SN54HC148		SN74HC148		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V_{OH}	High-level output voltage	I_{OH} = – 20 μA	2	1.9	1.998		1.9		1.9		V
			4.5	4.4	4.499		4.4		4.4		
			6	5.9	5.999		5.9		5.9		
		I_{OH} = – 4 mA	4.5	3.98	4.3		3.7		3.84		
		I_{OH} = – 5.2 mA	6	5.48	5.8		5.2		5.34		
V_{OL}	Low-level output voltage	I_{OL} = 20 μA	2		0.002	0.1		0.1		0.1	V
			4.5		0.001	0.1		0.1		0.1	
			6		0.001	0.1		0.1		0.1	
		I_{OL} = 4 mA	4.5		0.17	0.26		0.4		0.33	
		I_{OL} = 5.2 mA	6		0.15	0.26		0.4		0.33	
I_I	Input hold current	V_I = V_{CC} or 0	6		±0.1	±100		±1000		±1000	nA
I_{CC}	Supply current	V_I = V_{CC} or 0. I_O = 0	6			8		160		80	μA
C_i	Input capacitance		2 to 6		3	10		10		10	pF

(1) V_I = V_{IH} or V_{IL}, unless otherwise noted.

6.5 Switching Characteristics

C_L = 50pF, unless otherwise specified. See (Parameter Measurement Information)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	V_{CC}	T_A = 25°C			SN54HC148		SN74HC148		UNIT
					MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{pd}	Propagation Dealy	1-7	A0, A1, A2	2		69	180		270		225	ns
				4.5		23	36		54		45	
				6		21	31		46		38	
		0-7	EO	2		60	150		225		190	
				4.5		20	30		45		38	
				6		17	26		38		33	
			GS	2		75	190		285		240	
				4.5		25	38		57		48	
				6		21	32		48		41	
		EI	A0, A1, A2	2		78	195		295		245	
				4.5		26	39		59		49	
				6		22	33		50		42	
			GS	2		57	145		220		180	
				4.5		19	29		44		36	
				6		16	25		38		31	
			EO	2		66	165		250		205	
				4.5		22	33		50		41	
				6		19	28		43		35	
t_t	Transition time		Any	2		28	75		110		95	ns
				4.5		8	15		22		19	
				6		6	13		19		16	

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6.6 Operating Characteristics

T_A = 25°C

		Test Conditions	TYP	UNIT
C_{pd}	Power dissipation capacitance	No load	35	pF

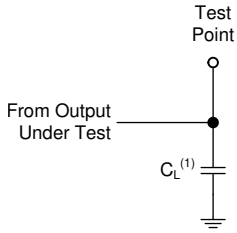
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7 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_t < 6 ns.

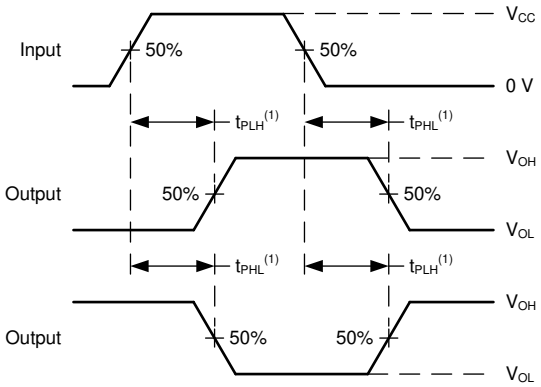
For clock inputs, f_{max} is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



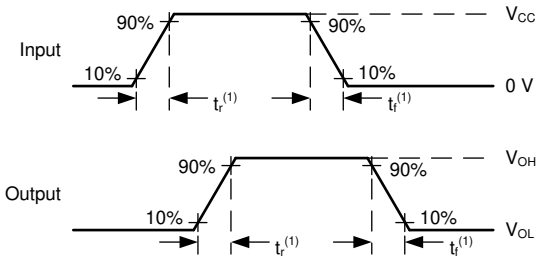
(1) C_L includes probe and test-fixture capacitance.

图 7-1. Load Circuit for Push-Pull Outputs



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd}.

图 7-2. Voltage Waveforms, Propagation Delays for Standard CMOS Inputs



(1) The greater between t_r and t_f is the same as t_t.

图 7-3. Voltage Waveforms, Input and Output Transition Times for Standard CMOS Inputs

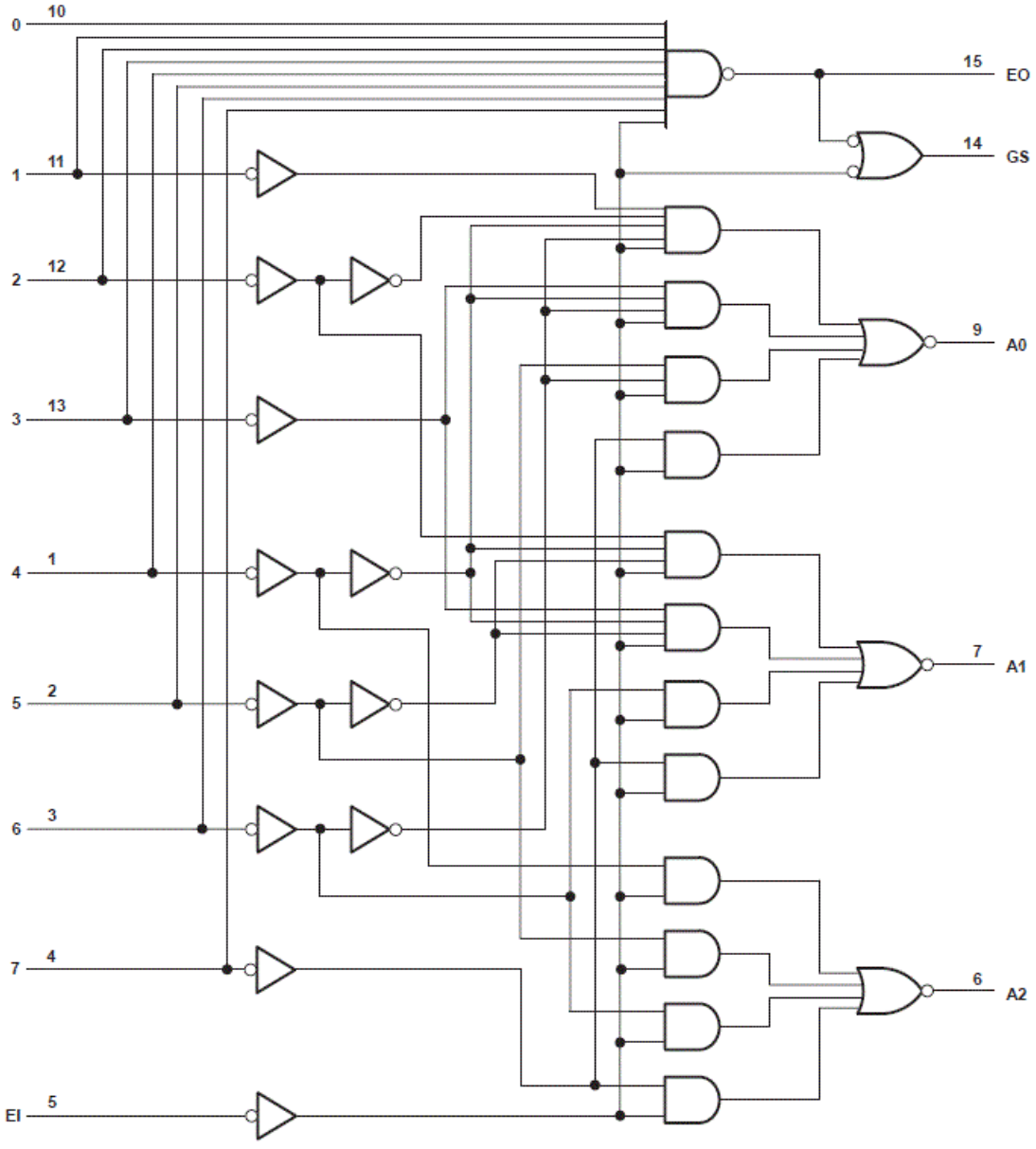
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8 Detailed Description

8.1 Overview

The ’HC148 devices feature priority decoding of the inputs to ensure that only the highest-order data line is encoded. These devices encode eight data lines to 3-line (4-2-1) binary (octal). Cascading circuitry (enable input EI and enable output EO) has been provided to allow octal expansion without the need for external circuitry. Data inputs and outputs are active at the low logic level.

8.2 Functional Block Diagram



Pin numbers shown are for the D, DW, J, N, NS, and W packages.

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8.3 Device Functional Modes

表 8-1. Function Table

INPUTS									OUTPUTS				
EI	0	1	2	3	4	5	6	7	A2	A1	A0	GS	EO
H	X	X	X	X	X	X	X	X	H	H	H	H	H
L	H	H	H	H	H	H	H	H	H	H	H	H	L
L	X	X	X	X	X	X	X	L	L	L	L	L	H
L	X	X	X	X	X	X	L	H	L	L	H	L	H
L	X	X	X	X	X	L	H	H	L	H	L	L	H
L	X	X	X	X	L	H	H	H	L	H	H	L	H
L	X	X	X	L	H	H	H	H	H	L	L	L	H
L	X	X	L	H	H	H	H	H	H	L	H	L	H
L	X	L	H	H	H	H	H	H	H	H	L	L	H
L	L	H	H	H	H	H	H	H	H	H	H	L	H

9 Application Information

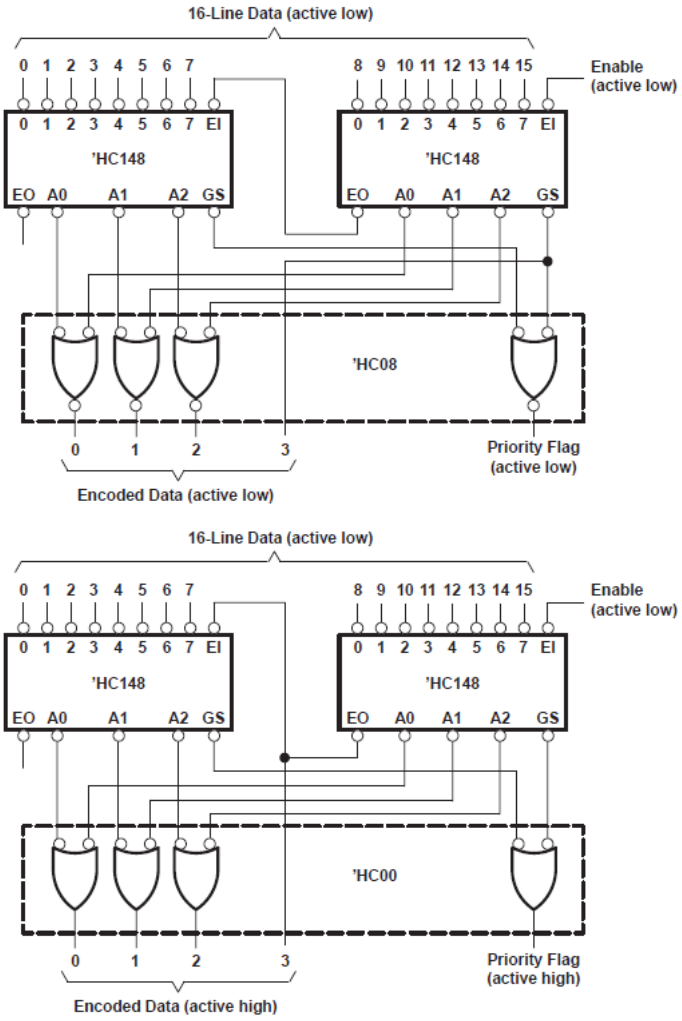


图 9-1. Priority Encoder for 16 Bits

Because the ’ HC148 devices are combinational logic circuits, wrong addresses can appear during input transients. Moreover, a change from high to low at EI can cause a transient low on GS when all inputs are high. This must be considered when strobing the outputs.

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10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-μF capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1-μF and 1-μF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

11 Layout

11.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC}, whichever makes more sense for the logic function or is more convenient.

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12 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

12.1 Documentation Support

12.1.1 Related Documentation

12.2 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 *订阅更新* 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

12.3 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

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12.4 Trademarks

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12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 术语表

TI 术语表　　本术语表列出并解释了术语、首字母缩略词和定义。

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN54HC148J	Active	Production	CDIP (J) | 16	25 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC148J
SN54HC148J.A	Active	Production	CDIP (J) | 16	25 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC148J
SN74HC148DR	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 85	HC148
SN74HC148DR.A	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC148
SN74HC148DRE4	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC148
SN74HC148DRG4	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC148
SN74HC148DRG4.A	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC148
SN74HC148N	NRND	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC148N
SN74HC148N.A	NRND	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC148N
SN74HC148NSR	Active	Production	SOP (NS) | 16	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC148
SN74HC148NSR.A	Active	Production	SOP (NS) | 16	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC148
SNJ54HC148FK	Active	Production	LCCC (FK) | 20	55 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SNJ54HC 148FK
SNJ54HC148FK.A	Active	Production	LCCC (FK) | 20	55 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SNJ54HC 148FK
SNJ54HC148J	Active	Production	CDIP (J) | 16	25 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SNJ54HC148J
SNJ54HC148J.A	Active	Production	CDIP (J) | 16	25 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SNJ54HC148J

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF SN54HC148, SN74HC148 :

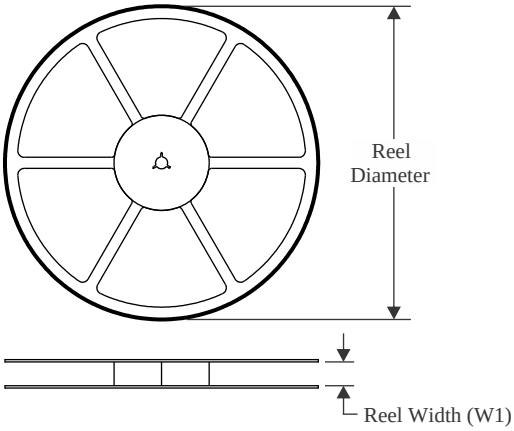
- Catalog : SN74HC148
- Military : SN54HC148

NOTE: Qualified Version Definitions:

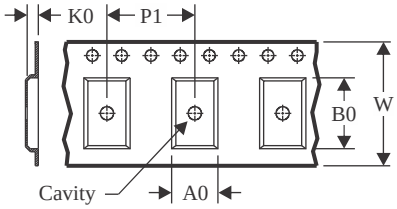
- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS

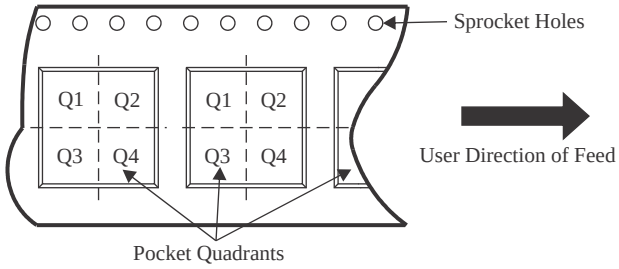


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

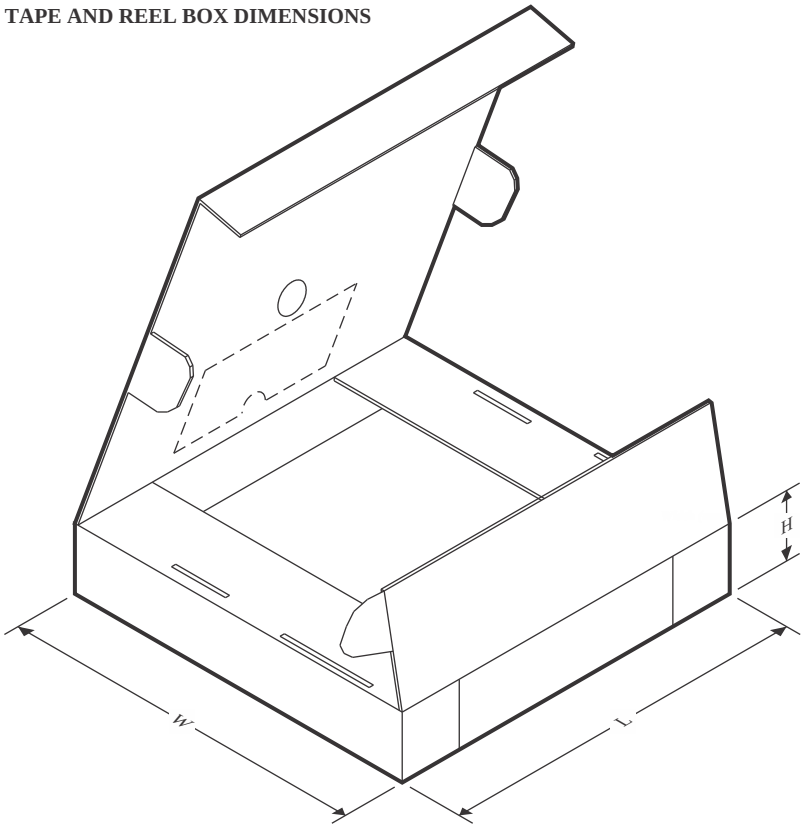
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC148DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HC148DRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HC148NSR	SOP	NS	16	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1

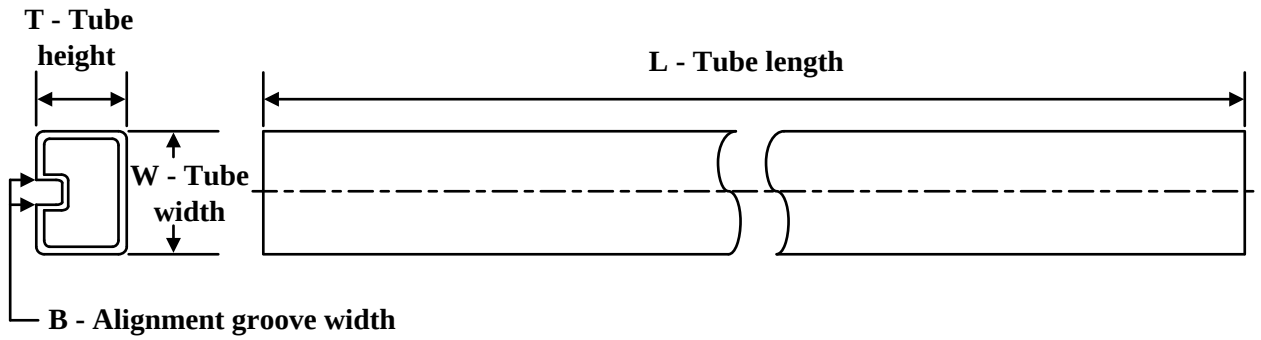
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

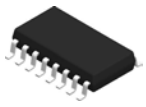
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC148DR	SOIC	D	16	2500	353.0	353.0	32.0
SN74HC148DRG4	SOIC	D	16	2500	340.5	336.1	32.0
SN74HC148NSR	SOP	NS	16	2000	353.0	353.0	32.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74HC148N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC148N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC148N.A	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC148N.A	N	PDIP	16	25	506	13.97	11230	4.32
SNJ54HC148FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54HC148FK.A	FK	LCCC	20	55	506.98	12.06	2030	NA

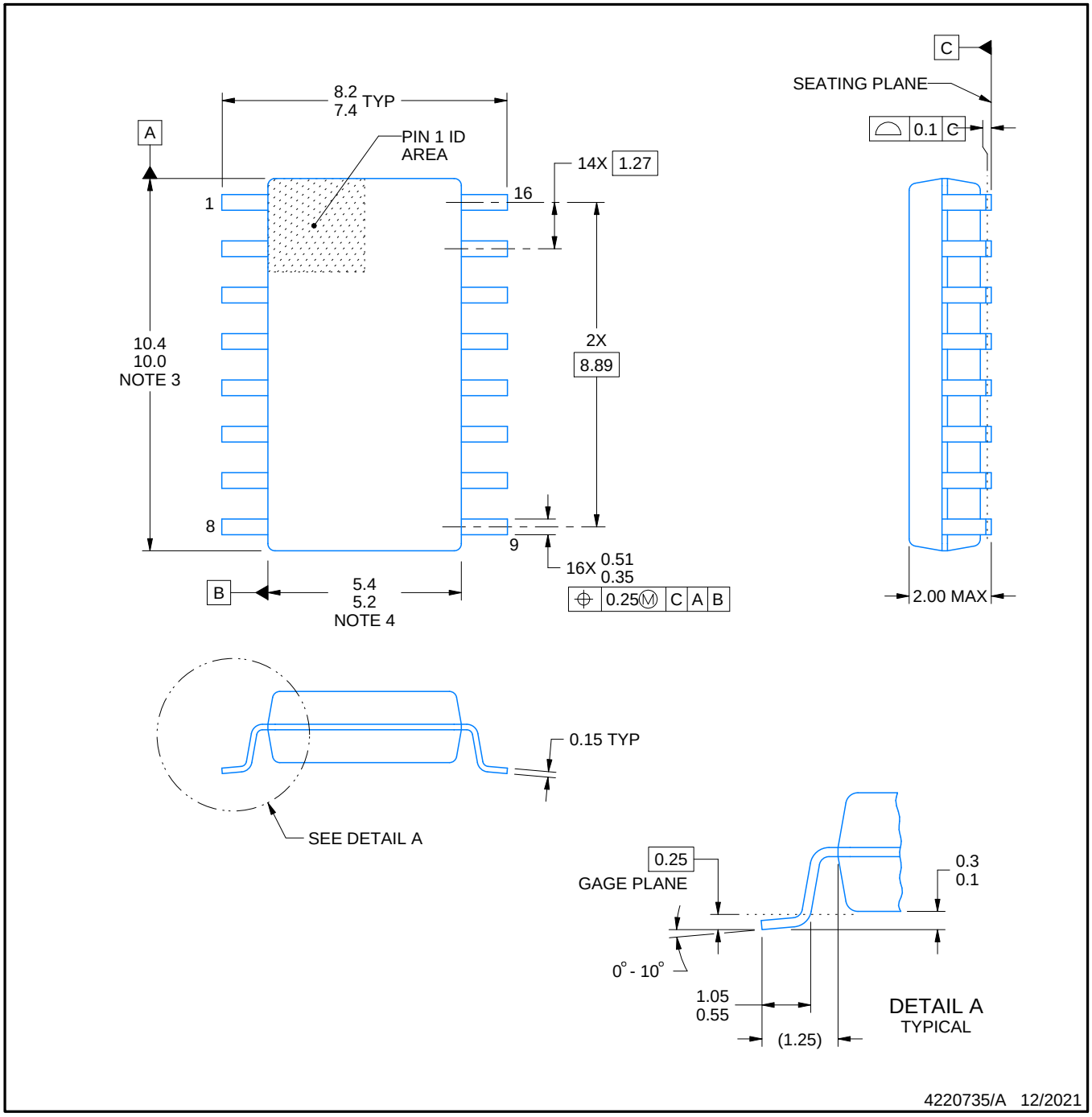


PACKAGE OUTLINE

NS0016A

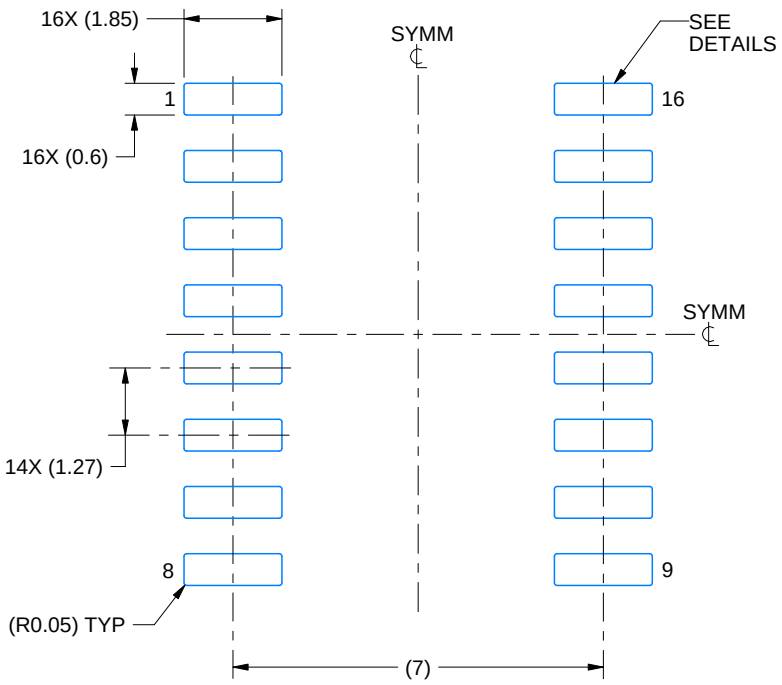
SOP - 2.00 mm max height

SOP

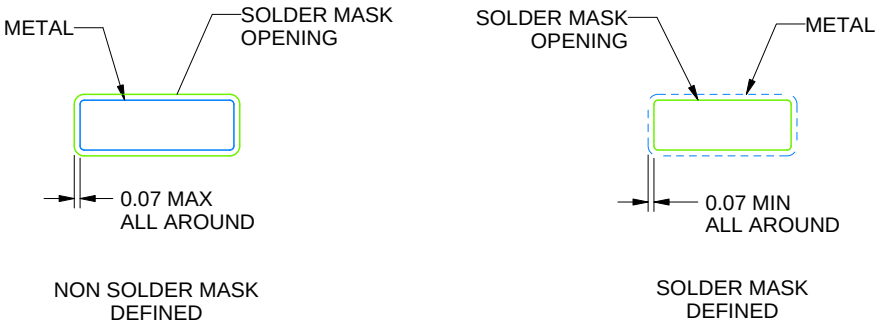


NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



LAND PATTERN EXAMPLE
SCALE:7X



NON SOLDER MASK
DEFINED

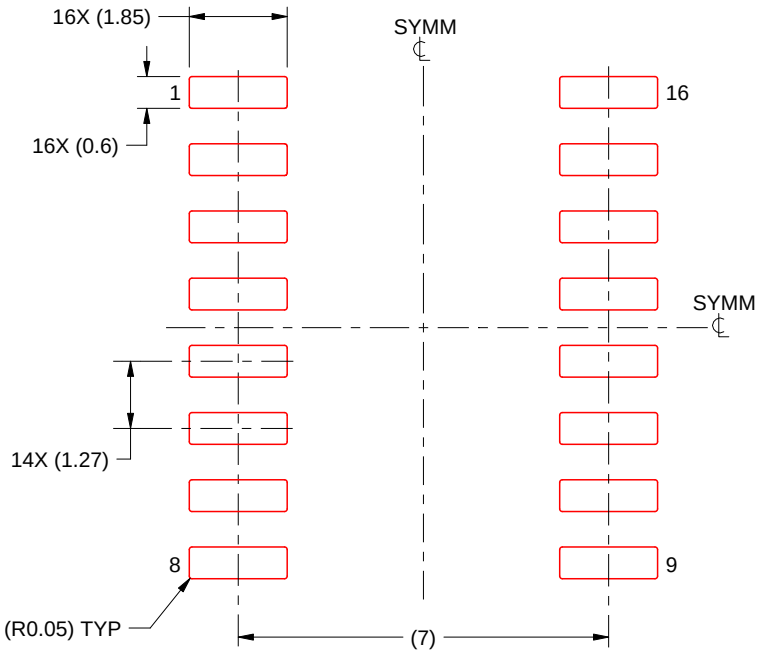
SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4220735/A 12/2021

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



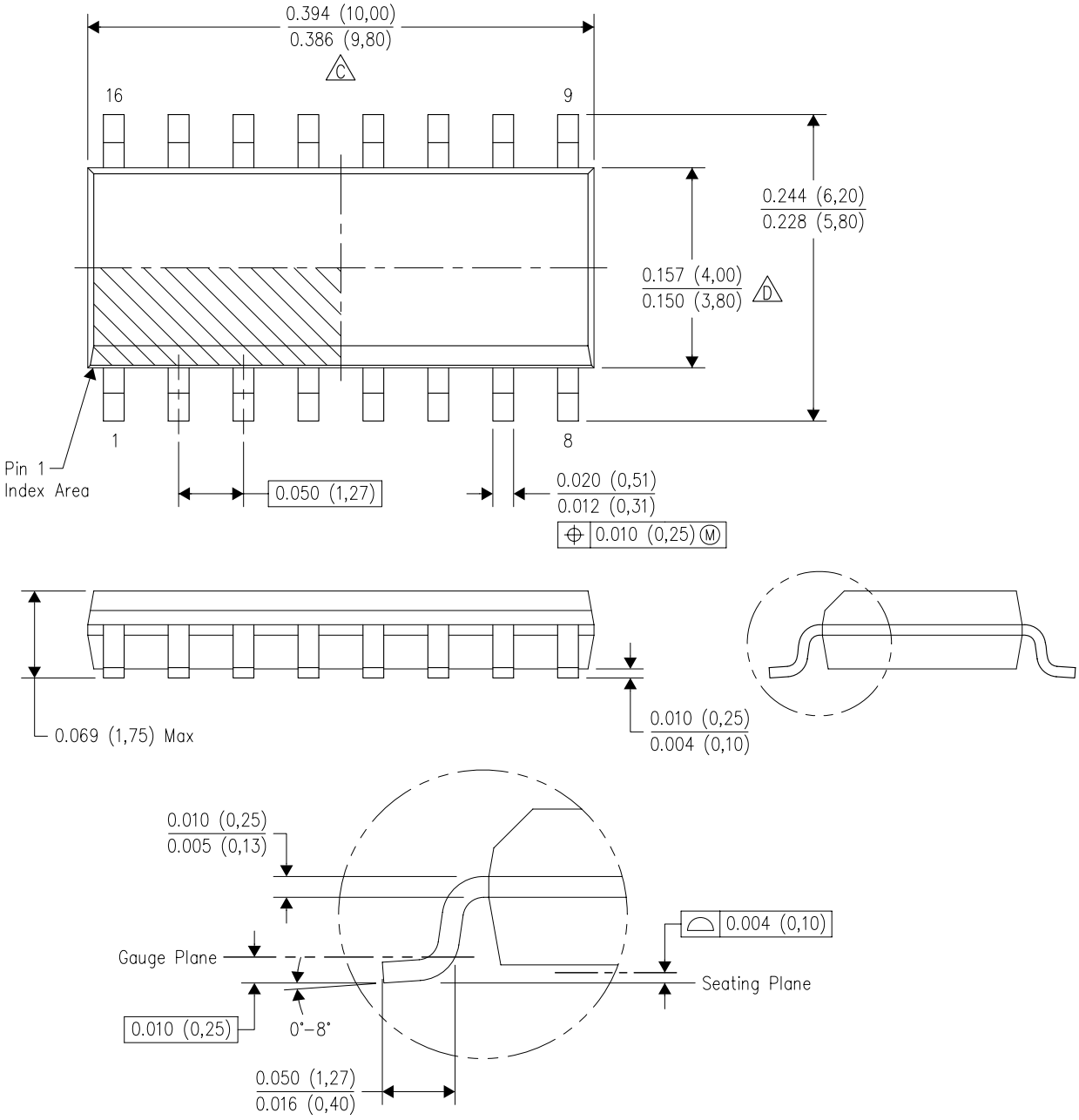
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:7X

4220735/A 12/2021

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

D (R–PDSO–G16) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AC.

GENERIC PACKAGE VIEW

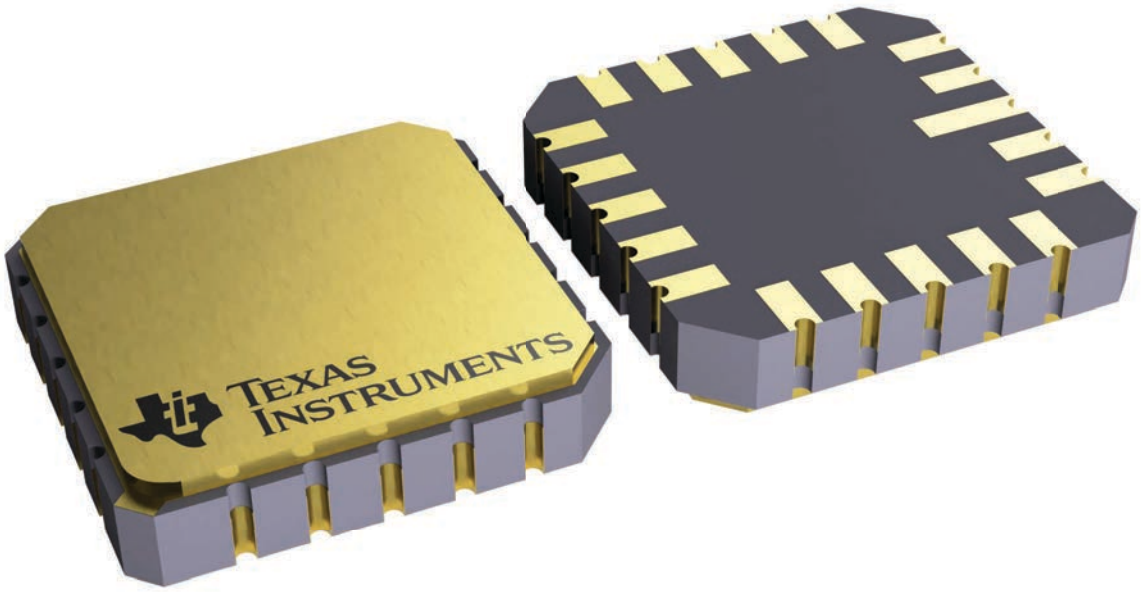
FK 20

LCCC - 2.03 mm max height

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

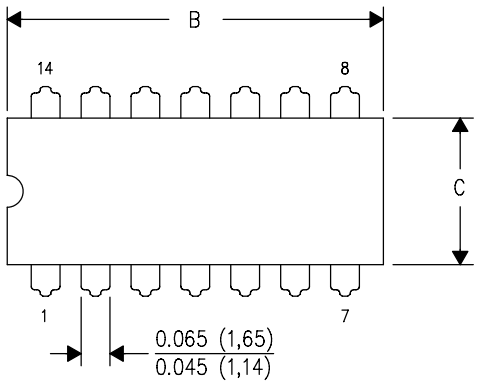


4229370VA\

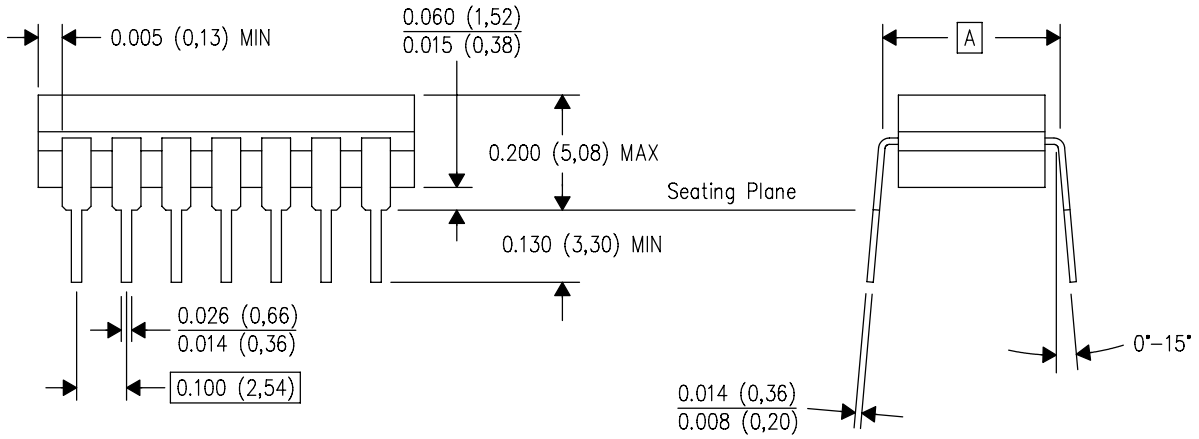
J (R–GDIP–T**)

14 LEADS SHOWN

CERAMIC DUAL IN–LINE PACKAGE



DIM \ PINS **	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



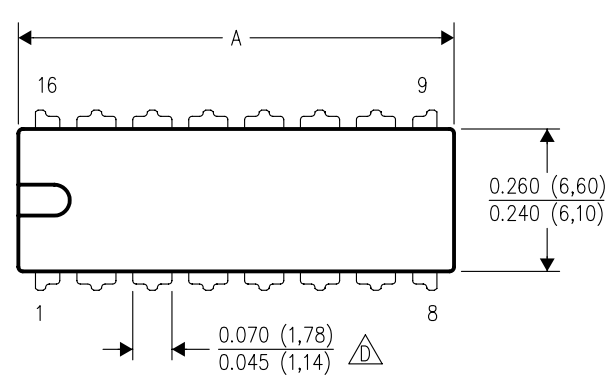
4040083/F 03/03

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package is hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
E. Falls within MIL STD 1835 GDIP1–T14, GDIP1–T16, GDIP1–T18 and GDIP1–T20.

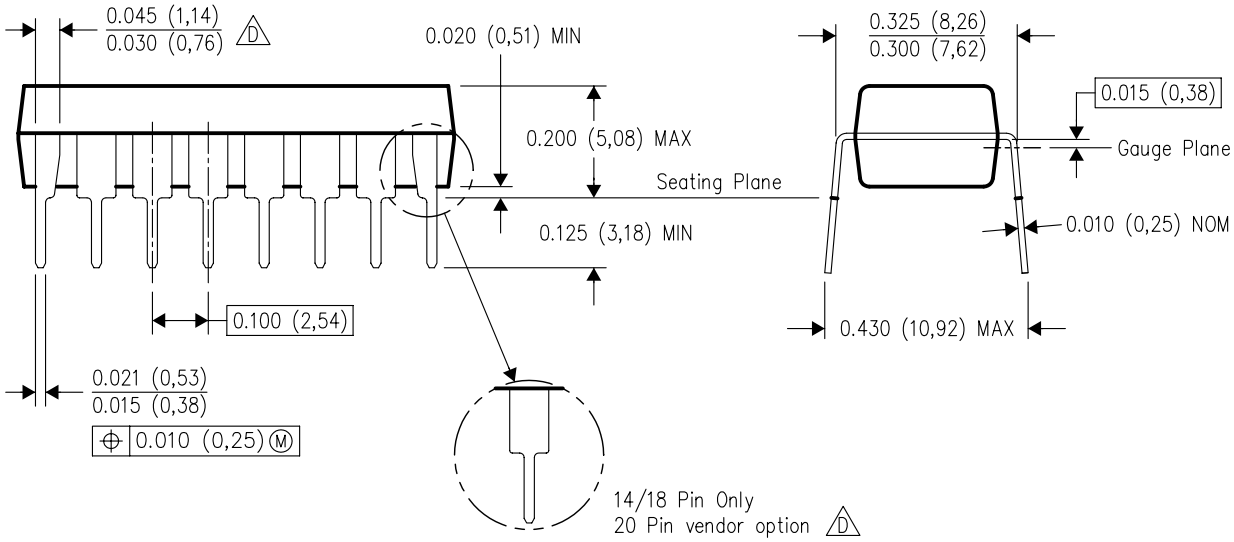
N (R–PDIP–T**)

PLASTIC DUAL–IN–LINE PACKAGE

16 PINS SHOWN



DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS–001 VARIATION (C)	AA	BB	AC	AD



4040049/E 12/2002

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

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